

COMPLIANT

N-Channel 60 V (D-S) Super Junction MOSFET

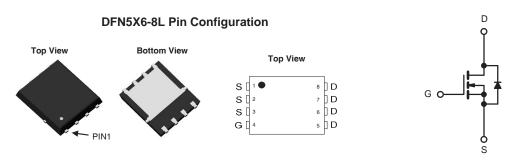
| PRODUCT SUMMARY | | | | | |
|---------------------|--------------------------------|---------------------------------|-----------------------|--|--|
| V _{DS} (V) | R _{DS(on)} (mΩ)(Typ.) | I _D (A) ^a | Q _g (Typ.) | | |
| 60 | 6.5 at V _{GS} = 10 V | 55 | 22 nC | | |
| 00 | 10 at V _{GS} = 4.5 V | - 55 | | | |

FEATURES

- **DT-SJ Power MOSFET**
- Very low on-resistance •
- Excellent gate charge x R_{DS(on)} ٠ product(FOM)

APPLICATIONS

- Power Management •
- Motor Drivers
- **DC-DC** Converters ٠



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted) | | | | | | |
|--|-------------------------|-----------------------------------|-----------------|------|--|--|
| Parameter | | Symbol | Limit | Unit | | |
| Drain-Source Voltage | | V _{DS} | 60 | V | | |
| Gate-Source Voltage | | V _{GS} | ± 20 | v | | |
| Continuous Drain Current (T ₁ = 150 °C) ^a | T _C = 25 °C | 1 | 55 | | | |
| $Continuous Drain Current (1) = 150^{-1}$ | T _C = 100 °C | ^I D | 36 | А | | |
| Pulsed Drain Current ^b | | I _{DM} | 220 | | | |
| Single Pulse Avalanche Energy | | E _{AS} | 350 | mJ | | |
| Maximum Power Dissipation ^c | T _C = 25 °C | PD | 65 ^c | W | | |
| | T _C = 100 °C | U I | 26 | | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to 150 | | | |
| Soldering Recommendations (Peak Temperature) | | | 260 | | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient ^d | t ≤ 10 s | R _{thJA} | - | 55 | °C/W |
| Maximum Junction-to-Case (Drain) | Steady State | R _{thJC} | - | 2.2 | 0/11 |

Notes

a. Calculated continuous current based on maximum allowablejunction temperature.

b. Repetitive rating; pulse width limited by max. junction temperature.

c. Pd is based on max. junction temperature, using junction-case thermal resistance.

d. The value of R_{0JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with Ta=25 °C.

DTQ6080N06SJ

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| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
|---------------------------------------|---------------------|---|------|------|-------|------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V_{GS} = 0 V, I_D = 250 μ A | 60 | - | - | V | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ | | - | 4 | v | |
| Gate-Body Leakage | I _{GSS} | V_{DS} = 0 V, V_{GS} = \pm 20 V $-$ | | - | ± 100 | nA | |
| Zara Cata Valtaga Drain Current | | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$ | - | - | 1 | | |
| Zero Gate Voltage Drain Current | IDSS | $V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ | | - | 10 | μA | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} = 5 V, V_{GS} = 10 V$ | 55 | - | - | Α | |
| Drain-Source On-State Resistance a | P | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$ | - | 6.5 | 8 | mΩ | |
| Drain-Source On-State Resistance ~ | R _{DS(on)} | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$ | - | 10 | 12.5 | | |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = 5 V, I_{D} = 20 A$ | - | 45 | - | S | |
| Dynamic ^b | | | -1 | | 1 | | |
| Input Capacitance | C _{iss} | | - | 1530 | - | pF | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V, V_{DS} = 30 V, f = 1MHz$ | - | 396 | - | | |
| Reverse Transfer Capacitance | C _{rss} | | - | 25 | - | | |
| Total Gate Charge ^c | Qg | | - | 22 | - | nC | |
| Gate-Source Charge ^c | Q _{gs} | $V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$ | - | 7.6 | - | | |
| Gate-Drain Charge ^c | Q _{gd} | | - | 2.5 | - | 1 | |
| Gate Resistance | Rg | f = 1 MHz | - | 1.5 | - | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | | - | 8 | - | | |
| Rise Time ^c | t _r | V_{DD} = 30 V, R _L = 1.5 Ω | - | 3 | - | | |
| Turn-Off Delay Time ^c | t _{d(off)} | $I_D = 20 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_g = 3 \Omega$ | - | 12 | - | ns | |
| Fall Time ^c | t _f | | - | 3 | - | | |
| Drain-Source Body Diode Ratings and | nd Characteris | stics ^b (T _C = 25 °C) | | | | | |
| Continuous Source Current | I _S | T _C = 25 °C | - | - | 55 | А | |
| Pulsed Source Current | I _{SM} | | - | - | 220 | А | |
| Forward Voltage ^a | V _{SD} | $I_{F} = 1 \text{ A}, V_{GS} = 0 \text{ V}$ | - | - | 1 | V | |
| Reverse Recovery Time | t _{rr} | L = 20.4 di/dt = 100.4/::0 | - | 30 | - | ns | |
| Reverse Recovery Charge | Q _{rr} | I _F = 20 A, di/dt = 100 A/μs | - | 29 | - | nC | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

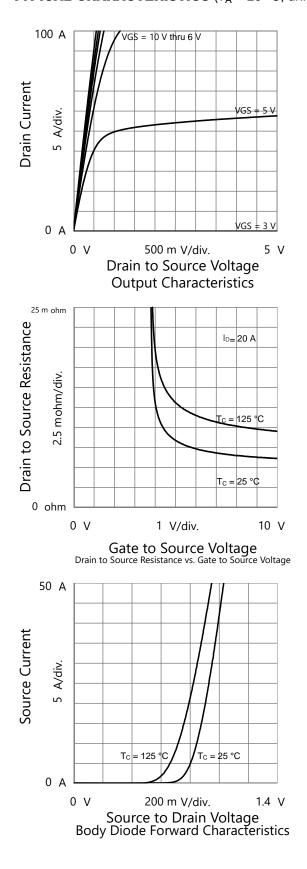
c. Independent of operating temperature.

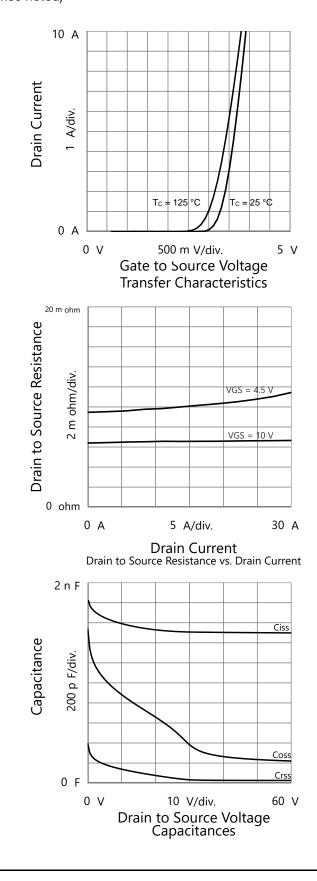
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

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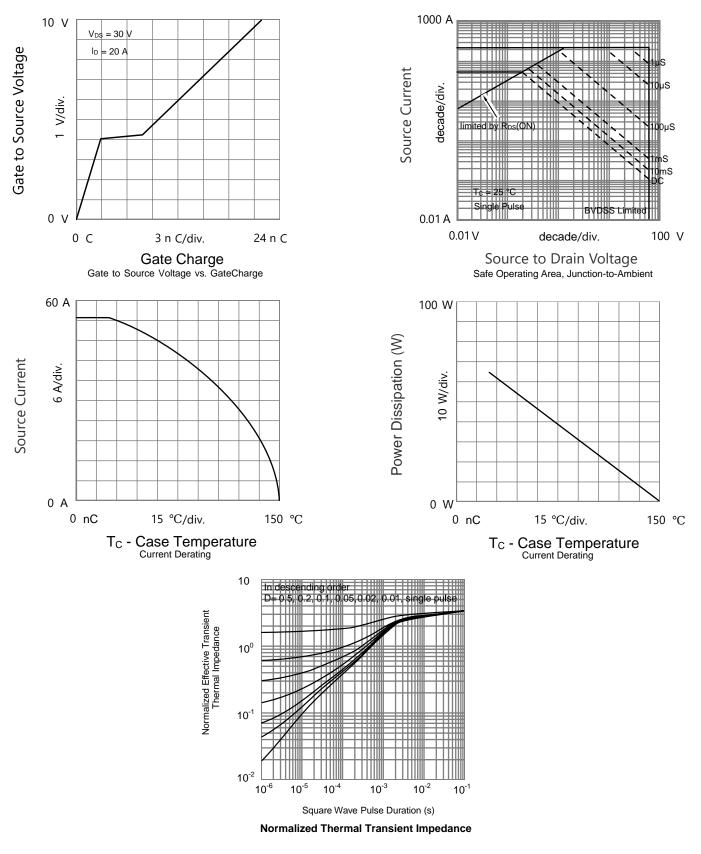




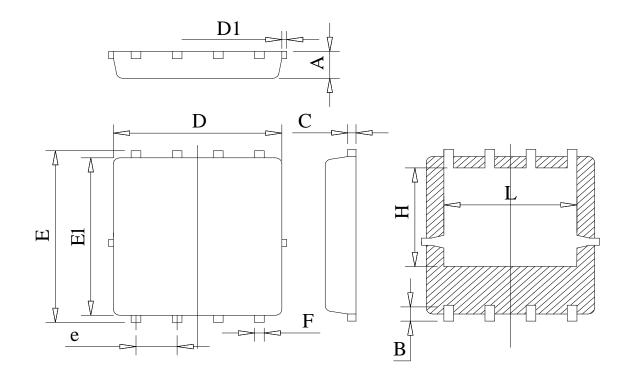
DTQ6080N06SJ

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



DFN5*6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

| Unit : mm | | | |
|-----------|------|-------|------|
| Symbol | Min | Тур | Max |
| A | 0.78 | 0.95 | 1.12 |
| В | 0.45 | 0.58 | 0.78 |
| С | 0.18 | 0.254 | 0.36 |
| D | 4.70 | 5.20 | 5.45 |
| D1 | | | 0.18 |
| Е | 5.85 | 6.05 | 6.25 |
| E1 | 5.38 | 5.55 | 5.98 |
| e | 1.15 | 1.27 | 1.40 |
| F | 0.18 | 0.30 | 0.52 |
| Н | 3.25 | 3.47 | 3.70 |
| L | 3.75 | 4.00 | 4.25 |



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